

PRELIMINARY - January 6, 1999

TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

# DESCRIPTION

The SC1185 combines a synchronous voltage mode controller with two low-dropout linear regulators providing most of the circuitry necessary to implement three DC/DC converters for powering advanced microprocessors such as Pentium<sup>®</sup> II.

The SC1185 switching section features an integrated 5 bit D/A converter, pulse by pulse current limiting, integrated power good signaling, and logic compatible shutdown. The SC1185 switching section operates at a fixed frequency of 140kHz, providing an optimum compromise between size, efficiency and cost in the intended application areas. The integrated D/A converter provides programmability of output voltage from 2.0V to 3.5V in 100mV increments and 1.30V to 2.05V in 50mV increments with no external components.

The SC1185 linear sections are low dropout regulators supplying 1.5V for GTL bus and 2.5V for non-GTL I/O. The Reference voltage is made available for external linear regulators.

# **FEATURES**

- Synchronous design, enables no heatsink solution
- 95% efficiency (switching section)
- 5 bit DAC for output programmability
- On chip power good function
- Designed for Intel Pentium<sup>®</sup> II requirements
- 1.5V, 2.5V @ 1% for linear section
- 1.265V ± 1.5% Reference available

### **APPLICATIONS**

- Pentium<sup>®</sup> II microprocessor supplies
- Flexible motherboards
- 1.3V to 3.5V microprocessor supplies
- Programmable triple power supplies

### **ORDERING INFORMATION**

Part Number <sup>(1)</sup>	Package	Linear Voltage	Temp. Range (T <sub>J</sub> )
SC1185CSW	SO-24	1.5V/2.5V	0° to 125°C
SC1185ACSW <sup>(2)</sup>	SO-24	1.5V/2.5V	0° to 125°C

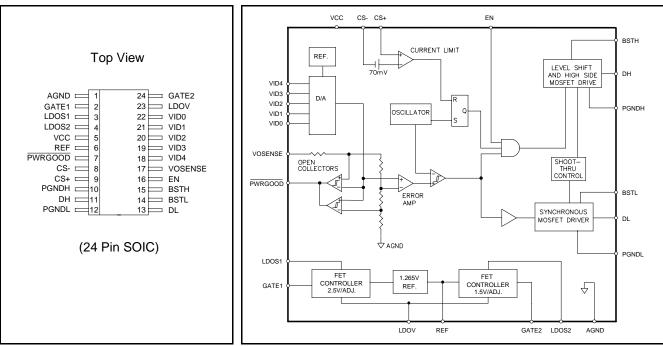
Note:

**BLOCK DIAGRAM** 

(1) Add suffix 'TR' for tape and reel.

(2) SC1185A provides improved output tolerance. See Output Voltage Table.

### **PIN CONFIGURATION**



Pentium is a registered trademark of Intel Corporation 1



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## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Maximum	Units
VCC to GND	V <sub>IN</sub>	-0.3 to +7	V
PGND to GND		± 1	V
BST to GND		-0.3 to +15	V
Operating Temperature Range	T <sub>A</sub>	0 to +70	°C
Junction Temperature Range	TJ	0 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	°C
Lead Temperature (Soldering) 10 seconds	TL	300	°C
Thermal Impedance Junction to Ambient	$\theta_{JA}$	80	°C/W
Thermal Impedance Junction to Case	θ <sub>JC</sub>	25	°C/W

### ELECTRICAL CHARACTERISTICS

Unless specified:  $V_{CC} = 4.75V$  to 5.25V; GND =  $P_{GND} = 0V$ ;  $V_{OSENSE} = V_{O}$ ; 0mV < (CS+-CS-) < 60mV; LDOV = 11.4V to 12.6V;  $T_A = 0$  to 70°C

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Switching Section	I			1	I.
Output Voltage I <sub>o</sub> = 2A in Application Circuit		See Output Voltage Table			
Supply Voltage	VCC	4.5		7	V
Supply Current	VCC = 5.0V		8	15	mA
Load Regulation	$I_{\rm O} = 0.8$ A to 15A		1		%
Line Regulation			±0.15		%
Current Limit Voltage		60	70	85	mV
Oscillator Frequency		125	140	160	kHz
Oscillator Max Duty Cycle		90	95		%
Peak DH Sink/Source Current	BSTH-DH = 4.5V, DH-PGNDH = 3.1V DH-PGNDH = 1.5V	1 100			A mA
Peak DL Sink/Source Current	BSTL-DL = 4.5V, DL-PGNDL = 3.1V DL-PGNDL = 1.5V	1 100			A mA
Gain (A <sub>oL</sub> )	VOSENSE to V <sub>o</sub>		35		dB
VID Source Current	$VIDx \le 2.4V$	1	10		μA
VID Leakage	VIDx = 5V			10	μA
Power good threshold voltage		88		112	%
Dead time		40	100		ns
Linear Sections					
Quiescent current	LDOV = 12V			5	mA
Output Voltage LDO1		2.469	2.500	2.531	V
Output Voltage LDO2		1.481	1.500	1.519	V
Reference Voltage	Iref ≤ 100µA	1.246	1.265	1.284	V
Gain (A <sub>oL</sub> )	LDOS (1,2) to GATE (1,2)		90		dB
Load Regulation	$I_0 = 0$ to 8A			0.3	%
Line Regulation				0.3	%
Output Impedance	$V_{GATE} = 6.5V$		1	1.5	kΩ
Gate Pulldown Impedance	GATE(1,2)-AGND;VCC=LDOV=0V	80	300	750	kΩ
VOSENSE Impedance		10			kΩ



SC1185 SC1185A

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### **PIN DESCRIPTION**

2   GATE1   Gate Drive Output LDO1     3   LDOS1   Sense Input for LDO2     4   LDOS2   Sense Input for LDO2     5   VCC   Input Voltage     6   REF   Buffered Reference Voltage output     7   PWRGOOD <sup>(1)</sup> Open collector logic output, high if V <sub>o</sub> within 10% of setpoint     8   CS-   Current Sense Input (negative)     9   CS+   Current Sense Input (positive)     10   PGNDH   Power Ground for High Side Switch     11   DH   High Side Driver Output     12   PGNDL   Power Ground for Low Side Switch     13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     15   BSTH   Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input	
3   LDOS1   Sense Input for LDO1     4   LDOS2   Sense Input for LDO2     5   VCC   Input Voltage     6   REF   Buffered Reference Voltage output     7   PWRGOOD <sup>(1)</sup> Open collector logic output, high if V <sub>o</sub> 8   CS-   Current Sense Input (negative)     9   CS+   Current Sense Input (positive)     10   PGNDH   Power Ground for High Side Switch     11   DH   High Side Driver Output     12   PGNDL   Power Ground for Low Side Switch     13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     15   BSTH   Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input     23   LDOV   +12V for LDO section   Note: <td></td>	
4   LDOS2   Sense Input for LDO2     5   VCC   Input Voltage     6   REF   Buffered Reference Voltage output     7   PWRGOOD <sup>(1)</sup> Open collector logic output, high if V <sub>o</sub> 7   PWRGOOD <sup>(1)</sup> Open collector logic output, high if V <sub>o</sub> 9   CS-   Current Sense Input (negative)     9   CS+   Current Sense Input (positive)     10   PGNDH   Power Ground for High Side Switch     11   DH   High Side Driver Output     12   PGNDL   Power Ground for Low Side Switch     13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     15   BSTH   Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input (LSB)     23   LDOV   +12V for LD	
5   VCC   Input Voltage     6   REF   Buffered Reference Voltage output     7   PWRGOOD <sup>(1)</sup> Open collector logic output, high if V <sub>o</sub> within 10% of setpoint     8   CS-   Current Sense Input (negative)     9   CS+   Current Sense Input (positive)     10   PGNDH   Power Ground for High Side Switch     11   DH   High Side Driver Output     12   PGNDL   Power Ground for Low Side Switch     13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input     23   LDOV   +12V for LDO section   (1) All I	
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7   PWRGOOD <sup>(1)</sup> within 10% of setpoint     8   CS-     9   CS+     10   PGNDH     11   DH     12   PGNDL     13   DL     14   BSTL     15   BSTH     16   EN <sup>(1)</sup> 17   VOSENSE     18   VID4 <sup>(1)</sup> 19   VID3 <sup>(1)</sup> 19   VID2 <sup>(1)</sup> 19   VID2 <sup>(1)</sup> 19   VID1 <sup>(1)</sup> 11   Programming Input     12   PGNDL     13   DL     14   BSTL     Supply for Low Side Driver     15   BSTH     Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE     19   VID3 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input	AG
9   CS+   Current Sense Input (positive)     10   PGNDH   Power Ground for High Side Switch     11   DH   High Side Driver Output     12   PGNDL   Power Ground for Low Side Switch     13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     15   BSTH   Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input (LSB)     23   LDOV   +12V for LDO section	GA
10PGNDHPower Ground for High Side Switch11DHHigh Side Driver Output12PGNDLPower Ground for Low Side Switch13DLLow Side Driver Output14BSTLSupply for Low Side Driver15BSTHSupply for High Side Driver16EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.17VOSENSETop end of internal feedback chain18VID4 <sup>(1)</sup> Programming Input20VID2 <sup>(1)</sup> Programming Input21VID1 <sup>(1)</sup> Programming Input22VID0 <sup>(1)</sup> Programming Input (LSB)23LDOV+12V for LDO sectionNote: (1) All I	LD(
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13   DL   Low Side Driver Output     14   BSTL   Supply for Low Side Driver     15   BSTH   Supply for High Side Driver     16   EN <sup>(1)</sup> Logic low shuts down the converter; High or open for normal operation.     17   VOSENSE   Top end of internal feedback chain     18   VID4 <sup>(1)</sup> Programming Input     20   VID2 <sup>(1)</sup> Programming Input     21   VID1 <sup>(1)</sup> Programming Input     22   VID0 <sup>(1)</sup> Programming Input (LSB)     23   LDOV   +12V for LDO section	(
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22     VID0 <sup>(1)</sup> Programming Input (LSB)     Note:       23     LDOV     +12V for LDO section     (1) All I	
23 LDOV +12V for LDO section (1) All I	
(.),	:
	II logic le
24 GATE2 Gate Drive Output LDO2 collector	ctor TTL

Top V	iew
AGND 1 GATE1 2 LDOS1 3 LDOS2 4 VCC 5 REF 6 PWRGOOD 7 CS- 8 CS+ 9 PGNDH 10 DH 11 PGNDL 12	24   GATE2     23   LDOV     22   VID0     21   VID1     20   VID2     19   VID3     18   VID4     17   VOSENSE     16   EN     15   BSTH     14   BSTL     13   DL
(24 Pin	SOIC)

I) All logic level inputs and outputs are open ollector TTL compatible.



# SC1185 SC1185A

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# OUTPUT VOLTAGE

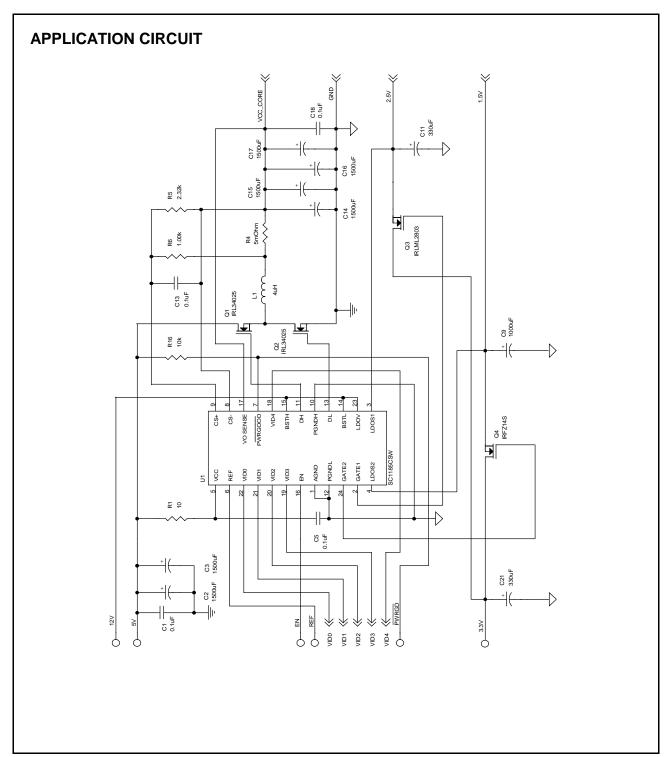
Unless specified: 4.75V < VCC < 5.25V; GND = PGND = 0V; VOSENSE =  $V_0$ ; 0mV < (CS+-CS-) < 60mV; = 0°C < T<sub>j</sub> < 85°C

			Standard		61	'A" Versio	n		
PARAMETER	<b>VID</b> 43210	MIN	TYP	MAX	MIN	TYP	MAX	UNITS	
Output Voltage	01111	1.277	1.300	1.323	1.287	1.300	1.313	V	
1 3	01110	1.326	1.350	1.374	1.337	1.350	1.364		
	01101	1.375	1.400	1.425	1.386	1.400	1.414		
	01100	1.424	1.450	1.476	1.436	1.450	1.465		
	01011	1.478	1.500	1.523	1.485	1.500	1.515		
	01010	1.527	1.550	1.573	1.535	1.550	1.566		
	01001	1.576	1.600	1.624	1.584	1.600	1.616		
	01000	1.625	1.650	1.675	1.634	1.650	1.667		
	00111	1.675	1.700	1.726	1.683	1.700	1.717		
	00110	1.724	1.750	1.776	1.733	1.750	1.768		
	00101	1.782	1.800	1.818	1.782	1.800	1.818		
	00100	1.832	1.850	1.869	1.832	1.850	1.869		
	00011	1.881	1.900	1.919	1.881	1.900	1.919		
	00010	1.931	1.950	1.970	1.931	1.950	1.970		
	00001	1.980	2.000	2.020	1.980	2.000	2.020		
	00000	2.030	2.050	2.071	2.030	2.050	2.071		
	11111	1.970	2.000	2.030	1.970	2.000	2.030		
	11110	2.069	2.100	2.132	2.069	2.100	2.132		
	11101	2.167	2.200	2.233	2.167	2.200	2.233		
	11100	2.266	2.300	2.335	2.266	2.300	2.335		
	11011	2.364	2.400	2.436	2.364	2.400	2.436		
	11010	2.463	2.500	2.538	2.463	2.500	2.538		
	11001	2.561	2.600	2.639	2.561	2.600	2.639		
	11000	2.660	2.700	2.741	2.660	2.700	2.741		
	10111	2.758	2.800	2.842	2.758	2.800	2.842		
	10110	2.842	2.900	2.958	2.842	2.900	2.958		
	10101	2.940	3.000	3.060	2.940	3.000	3.060		
	10100	3.038	3.100	3.162	3.038	3.100	3.162		
	10011	3.136	3.200	3.264	3.136	3.200	3.264		
	10010	3.234	3.300	3.366	3.234	3.300	3.366		
	10001	3.332	3.400	3.468	3.332	3.400	3.468		
	10000	3.430	3.500	3.570	3.430	3.500	3.570		



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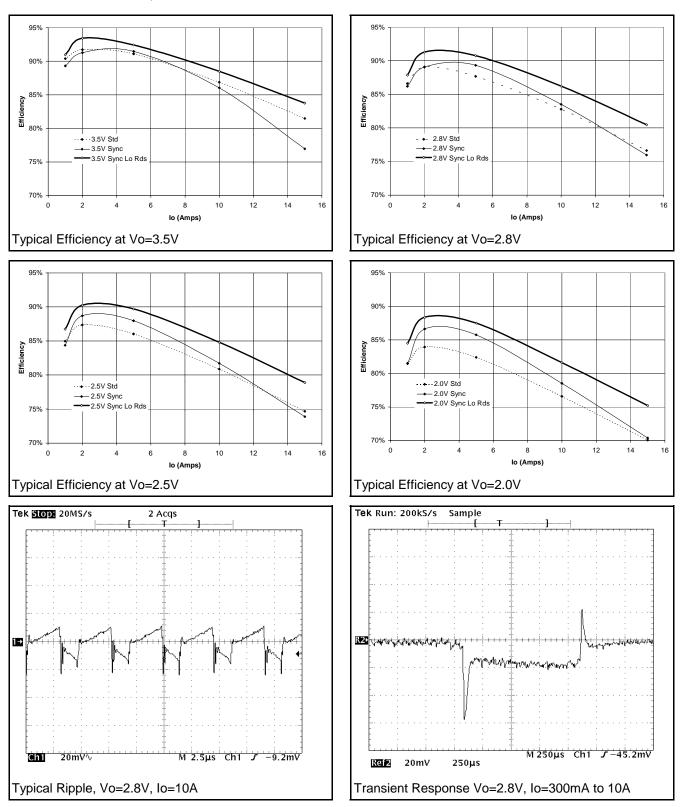
### **MATERIALS LIST**

Qty.	Reference	Part/Description	Vendor	Notes
4	C1,C5,C13,C18	0.1µF Ceramic	Various	
6	C2,C3,C14-C17	1500µF/6.3V	SANYO	MV-GX or equiv. Low ESR
1	C9	1000µF		
2	C11,C21	330µF/6.3V	Various	
1	L1	4µH		8 Turns 16AWG on MICROMETALS T50-52D core
2	Q1,Q2	See notes	See notes	FET selection requires trade-off between efficiency and cost. Absolute maximum $R_{DS(ON)} = 22 \text{ m}\Omega$ for Q1,Q2
1	Q3	IRLML2803	IR	.25Ω 30V SOT23 (or equavilent)
1	Q4	IRFZ14S	IR	Or equivalent
1	R4	5mΩ	IRC	OAR-1 Series
1	R5	2.32kΩ, 1%, 1/8W	Various	
1	R6	1kΩ, 1%, 1/8W	Various	
1	R1	10Ω, 5%, 1/8W	Various	
1	U1	SC1185CSW	SEMTECH	



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### LAYOUT GUIDELINES

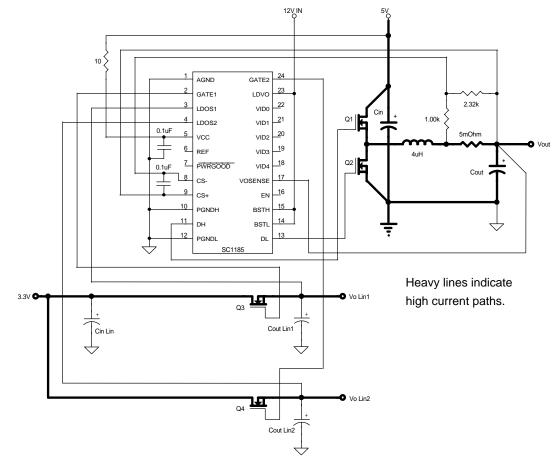
Careful attention to layout requirements are necessary for successful implementation of the SC1185 PWM controller. High currents switching at 140kHz are present in the application and their effect on ground plane voltage differentials must be understood and minimized.

1). The high power parts of the circuit should be laid out first. A ground plane should be used, the number and position of ground plane interruptions should be such as to not unnecessarily compromise ground plane integrity. Isolated or semi-isolated areas of the ground plane may be deliberately introduced to constrain ground currents to particular areas, for example the input capacitor and bottom FET ground.

2). The loop formed by the Input Capacitor(s) (Cin), the Top FET (Q1) and the Bottom FET (Q2) must be kept

as small as possible. This loop contains all the high current, fast transition switching. Connections should be as wide and as short as possible to minimize loop inductance. Minimizing this loop area will a) reduce EMI, b) lower ground injection currents, resulting in electrically "cleaner" grounds for the rest of the system and c) minimize source ringing, resulting in more reliable gate switching signals.

3). The connection between the junction of Q1, Q2 and the output inductor should be a wide trace or copper region. It should be as short as practical. Since this connection has fast voltage transitions, keeping this connection short will minimize EMI. The connection between the output inductor and the sense resistor should be a wide trace or copper area, there are no fast voltage or current transitions in this connection and length is not so important, however adding unnecessary impedance will reduce efficiency.



Layout diagram for the SC1185



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4) The Output Capacitor(s) (Cout) should be located as close to the load as possible, fast transient load currents are supplied by Cout only, and connections between Cout and the load must be short, wide copper areas to minimize inductance and resistance.

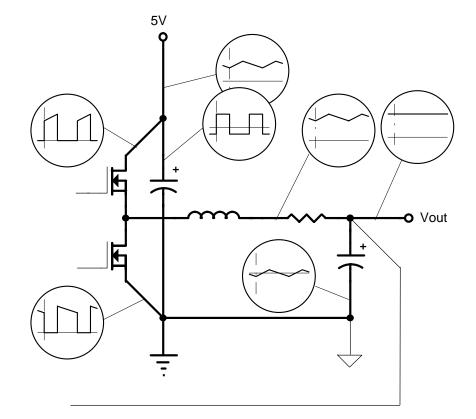
5) The SC1185 is best placed over a quiet ground plane area, avoid pulse currents in the Cin, Q1, Q2 loop flowing in this area. PGNDH and PGNDL should be returned to the ground plane close to the package. The AGND pin should be connected to the ground side of (one of) the output capacitor(s). If this is not possible, the AGND pin may be connected to the ground path between the Output Capacitor(s) and the Cin, Q1, Q2 loop. Under no circumstances should AGND be returned to a ground inside the Cin, Q1, Q2 loop.

6) Vcc for the SC1185 should be supplied from the 5V

supply through a  $10\Omega$  resistor, the Vcc pin should be decoupled directly to AGND by a  $0.1\mu$ F ceramic capacitor, trace lengths should be as short as possible.

7) The Current Sense resistor and the divider across it should form as small a loop as possible, the traces running back to CS+ and CS- on the SC1185 should run parallel and close to each other. The  $0.1\mu$ F capacitor should be mounted as close to the CS+ and CS- pins as possible.

8) Ideally, the grounds for the two LDO sections should be returned to the ground side of (one of) the output capacitor(s).



Currents in various parts of the power section



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### **COMPONENT SELECTION**

#### SWITCHING SECTION

OUTPUT CAPACITORS - Selection begins with the most critical component. Because of fast transient load current requirements in modern microprocessor core supplies, the output capacitors must supply all transient load current requirements until the current in the output inductor ramps up to the new level. Output capacitor ESR is therefore one of the most important criteria. The maximum ESR can be simply calculated from:

$$R_{ESR} \leq \frac{V_t}{I_*}$$

Where

V<sub>t</sub> = Maximum transient voltage excursion

I<sub>t</sub> = Transient current step

For example, to meet a 100mV transient limit with a 10A load step, the output capacitor ESR must be less than  $10m\Omega$ . To meet this kind of ESR level, there are three available capacitor technologies.

	Each Capacitor			To	tal
Technology	C (µF)	ESR (mΩ)	Qty. Rqd.	C (µF)	ESR (mΩ)
Low ESR Tantalum	330	60	6	2000	10
OS-CON	330	25	3	990	8.3
Low ESR Aluminum	1500	44	5	7500	8.8

The choice of which to use is simply a cost/performance issue, with Low ESR Aluminum being the cheapest, but taking up the most space.

INDUCTOR - Having decided on a suitable type and value of output capacitor, the maximum allowable value of inductor can be calculated. Too large an inductor will produce a slow current ramp rate and will cause the output capacitor to supply more of the transient load current for longer - leading to an output voltage sag below the ESR excursion calculated above. The maximum inductor value may be calculated from:

$$L \le \frac{R_{ESR} C}{I_{t}} \left( V_{IN} - V_{O} \right)$$

The calculated maximum inductor value assumes 100% duty cycle, so some allowance must be made. Choosing an inductor value of 50 to 75% of the calculated maximum will guarantee that the inductor current will ramp

fast enough to reduce the voltage dropped across the ESR at a faster rate than the capacitor sags, hence ensuring a good recovery from transient with no additional excursions.

We must also be concerned with ripple current in the output inductor and a general rule of thumb has been to allow 10% of maximum output current as ripple current. Note that most of the output voltage ripple is produced by the inductor ripple current flowing in the output capacitor ESR. Ripple current can be calculated from:

$$I_{L_{RIPPLE}} = \frac{V_{IN}}{4 \cdot L \cdot f_{OSC}}$$

Ripple current allowance will define the minimum permitted inductor value.

POWER FETS - The FETs are chosen based on several criteria with probably the most important being power dissipation and power handling capability. TOP FET - The power dissipation in the top FET is a combination of conduction losses, switching losses and bottom FET body diode recovery losses.

a) Conduction losses are simply calculated as:

$$\mathsf{P}_{\mathsf{COND}} = \mathsf{I}_{\mathsf{O}}^2 \cdot \mathsf{R}_{\mathsf{DS(on)}} \cdot \delta$$
  
where

$$\delta = \text{duty cycle} \approx \frac{V_O}{V_{IN}}$$

b) Switching losses can be estimated by assuming a switching time, if we assume 100ns then:

$$P_{_{SW}}~=I_{_{O}}\,\cdot\,V_{_{IN}}\,\cdot10^{-2}$$

or more generally,

$$\mathsf{P}_{\mathsf{SW}} = \frac{\mathsf{I}_{\mathsf{O}} \cdot \mathsf{V}_{\mathsf{IN}} \cdot (\mathsf{t}_{\mathsf{r}} + \mathsf{t}_{\mathsf{f}}) \cdot \mathsf{f}_{\mathsf{OSC}}}{4}$$

c) Body diode recovery losses are more difficult to estimate, but to a first approximation, it is reasonable to assume that the stored charge on the bottom FET body diode will be moved through the top FET as it starts to turn on. The resulting power dissipation in the top FET will be:

$$\mathsf{P}_{\mathsf{R}\mathsf{R}} \; = \mathsf{Q}_{\mathsf{R}\mathsf{R}} \; \cdot \mathsf{V}_{\mathsf{I}\mathsf{N}} \; \cdot \mathsf{f}_{\mathsf{OSC}}$$

To a first order approximation, it is convenient to only consider conduction losses to determine FET suitability. For a 5V in; 2.8V out at 14.2A requirement, typical FET losses would be:



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Using 1.5X Room temp  $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})}$  to allow for temperature rise.

FET type	$R_{DS(on)}(m\Omega)$	$P_D(W)$	Package
IRL34025	15	1.69	D <sup>2</sup> PAK
IRL2203	10.5	1.19	D <sup>2</sup> PAK
Si4410	20	2.26	SO-8

BOTTOM FET - Bottom FET losses are almost entirely due to conduction. The body diode is forced into conduction at the beginning and end of the bottom switch conduction period, so when the FET turns on and off, there is very little voltage across it, resulting in low switching losses. Conduction losses for the FET can be determined by:

$$P_{\text{COND}} = I_{\text{O}}^2 \cdot R_{\text{DS(on)}} \cdot (1 - \delta)$$

For the example above:

FET type	$R_{DS(on)}(m\Omega)$	$P_D(W)$	Package
IRL34025	15	1.33	D <sup>2</sup> PAK
IRL2203	10.5	0.93	D <sup>2</sup> PAK
Si4410	20	1.77	SO-8

Each of the package types has a characteristic thermal impedance, for the TO-220 package, thermal impedance is mostly determined by the heatsink used. For the surface mount packages on double sided FR4, 2 oz printed circuit board material, thermal impedances of  $40^{\circ}$ C/W for the D<sup>2</sup>PAK and  $80^{\circ}$ C/W for the SO-8 are readily achievable. The corresponding temperature rise is detailed below:

	Temperature rise (°C)			
FET type	Top FET	Bottom FET		
IRL34025	67.6	53.2		
IRL2203	47.6	37.2		
Si4410	180.8	141.6		

It is apparent that single SO-8 Si4410 are not adequate for this application, but by using parallel pairs in each position, power dissipation will be approximately halved and temperature rise reduced by a factor of 4.

INPUT CAPACITORS - since the RMS ripple current in the input capacitors may be as high as 50% of the output current, suitable capacitors must be chosen accordingly. Also, during fast load transients, there may be restrictions on input di/dt. These restrictions require useable energy storage within the converter circuitry, either as extra output capacitance or, more usually, additional input capacitors. Choosing low ESR input capacitors will help maximize ripple rating for a given size.



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# **OUTLINE DRAWING**

